

Current Transducer HXS 10-NP/SP3

For the electronic measurement of currents: DC, AC, pulsed..., with galvanic separation between the primary circuit and the secondary circuit.







All data are given with $R_1 = 10 \text{ k}\Omega$

Electrical data

I_{PN}	Primary nominal RMS current		Serial	Parallel
1 14			±10	±20 A
			Serial	Parallel
I_{PM}	Primary current, measi	uring range	±30	±60 A
G_{th}	Theoretical sensitivity		0.62	5 V/I _{PN}
V_{out}	Output voltage (Analog	g) @ I _P	$V_{\text{OE}} \pm$	$E(0.625 \cdot I_{P}/I_{PN})V$
V_{ref}	Reference voltage 1)	Output voltage	2.5 ±	0.025 V
		Output impedance	Тур.	200 Ω
		Load impedance	200	kΩ
R_{L}	Load resistance		2	kΩ
R_{out}	Output internal resistar	nce	< 5	Ω
C_{L}	Capacitive loading (±2	0 %)	4.7	nF
$U_{\rm c}$	Supply voltage (±5 %)	2)	5	V
I_{C}	Current consumption @ $U_{\rm C}$ = 5 V		19	mA

Accuracy - Dynamic performance data

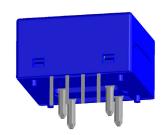
X	Accuracy ³⁾ @ I_{PN} , T_{A} = 25 °C		±1	%
$arepsilon_{L}$	Linearity error $0 \dots I_{PN}$		±0.5	%
	0 3 ×	I_{PN}	±1	%
TCV_{OE}	Temperature of coefficient of $V_{\rm O}$	_E (+25 85 °C)	±0.4	mV/K
		(-40 +25 °C)	±0.525	mV/K
TCV_{ref}	Temperature of coefficient of $V_{\rm p}$	_{ef} (+25 85 °C)	±0.01	%/K
		(-40 +25 °C)	±0.015	mV/K
TCV_{OF}/V_{OF}	Temperature of coefficient of $V_{\rm O}$	$_{\rm E}/V_{\rm ref}$	±0.15	mV/K
TCG	Temperature of coefficient of G		±0.05 % of re	ading/K
V_{OE}	Electrical offset voltage @ I_P = 0), $T_{A} = 25 ^{\circ}\text{C}$	$V_{\rm ref} \pm 0.0125$	V
V_{OM}	Magnetic offset voltage @ $I_P = 0$)		
	after an	overload of $3 \times I_{PN}$	±0.7	%
V_{no}	Output RMS noise voltage	(DC 10 kHz)	< 20	mVpp
		(DC 1 MHz)	< 40	mVpp
$t_{\sf ra}$	Reaction time to 10 % of I_{PN}		< 3	μs
t _r	Step response time to 90 % of I	4) P N	< 5	μs
BW	Frequency bandwidth (-3 dB) 5)		DC 50	kHz

- Notes: 1) It is possible to overdrive V_{ref} with an external reference voltage between 1.5 - 2.8 V providing its ability to sink or source approximately
 - ²⁾ Maximum supply voltage (not operating) < 6.5 V
 - ³⁾ Excluding offset and magnetic offset voltage
 - 4) For a $di/dt = 50 \text{ A/}\mu\text{s}$

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⁵⁾ Small signal only to avoid excessive heatings of the magnetic core.

I_{PN} = 10, 20 A **DUAL PHASE**



Features

- · Hall effect measuring principle
- Multirange current transducer through PCB pattern lay-out
- Galvanic separation between primary and secondary circuit
- Insulation test voltage 3500 V
- Extremely low profile < 11 mm
- Fixed offset & sensitivity
- Low power consumption
- Single power supply +5 V
- Insulating plastic case recognized according to UL 94-V0.

Special feature

 Two separate primary windings for dual phase measurement.

Advantages

- · Small size and space saving
- Only one design for wide current ratings range
- High immunity to external interference
- V_{ref} IN/OUT.

Applications

- · AC variable speed drives and servo motor drives
- Static converters for DC motor drives
- Battery supplied applications
- Uninterruptible Power Supplies (UPS)
- · Switched Mode Power Supplies (SMPS)

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 Power supplies for welding applications.

Application domain

Industrial.

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LEM reserves the right to carry out modifications on its transducers, in order to improve them, without prior notice



Current Transducer HXS 10-NP/SP3

General data		
$T_{\rm A}$ Ambient operating temperature $T_{\rm S}$ Ambient storage temperature m Mass Standard	-40 +85 -40 +85 10 EN 50178: 1997	°C °C g

In	Insulation coordination				
U_{d}	RMS voltage for AC insulation test, 50 Hz, 1 min				
u	Primary to secondary	3.5	kV		
	Primary 1 to primary 2	2.5	kV		
		Min			
d_{Cn}	Creepage distance	5.5	mm		
$d_{ extsf{Cp}} \ d_{ extsf{Cl}}$	Clearance	5.5	mm		
CTI	Comparative tracking index (group I)	600			

Applications examples

According to EN 50178 and IEC 61010-1 standards and following conditions:

- Over voltage category OV 3
- Pollution degree PD2
- Non-uniform field

According to UL 508 standards and following conditions: Maximum voltage 600 V

- Over voltage category OV 3
- Pollution degree PD2

	EN 50178	IEC 61010-1
$d_{\mathrm{Cp}},d_{\mathrm{CI}},\hat{U}_{\mathrm{W}}$	Rated insulation voltage	Nominal voltage
Basic insulation	600 V	300 V
Reinforced insulation	300 V	150 V

Safety

This transducer must be used in limited-energy secondary circuits according to IEC 61010-1.



This transducer must be used in electric/electronic equipment with respect to applicable standards and safety requirements in accordance with the manufacturer's operating instructions.



Caution, risk of electrical shock

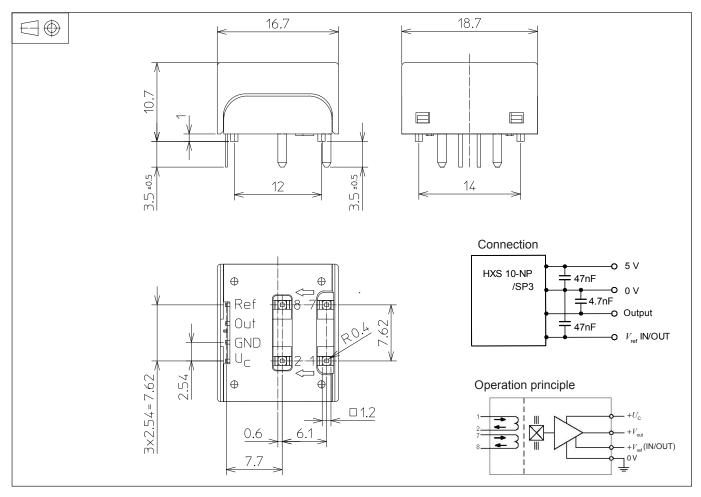
When operating the transducer, certain parts of the module can carry hazardous voltage (e.g. primary busbar, power supply). Ignoring this warning can lead to injury and/or cause serious damage.

This transducer is a build-in device, whose conducting parts must be inaccessible after installation. A protective housing or additional shield could be used. Main supply must be able to be disconnected.

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Dimensions HXS 10-NP/SP3 (in mm)



Primary connections	Primary RMS current		Resistance of	Insertion	B	
	nominal / _{PN} [A]	maximum / _{PN} [A]	primary winding $R_{\rm p}$ [mW]			
Serial	10	30	0.2	0.1	IN 1 7 0 0 0 0 2 8 OUT	
Parallel	20	60	0.05	0.025	IN 1 7 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0	

Mechanical characteristics

• General tolerance ±0.2 mm

Transducer fastening & connection of primary jumper 4 pins × 1.2 mm (corner R 0.4 mm)

Transducer fastening & connection of primary jumper
 4 pins × 1.2 mm (corner R 0.4 mm)

Recommended PCB hole

Primary PCB holeSecondary PCB holeØ 1.5 mmØ 0.7 mm

Remarks

- $V_{\rm out}$ is positive when $I_{\rm P}$ flows from terminals 1,7 (IN) to terminals 2,8 (OUT).
- Temperature of the primary conductor should not exceed
 100 °C
- Installation of the transducer must be done unless otherwise specified on the datasheet, according to LEM Transducer Generic Mounting Rules. Please refer to LEM document N°ANE120504 available on our Web site: Products/Product Documentation.

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单击下面可查看定价,库存,交付和生命周期等信息

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